

## Description

### EC70R65E N-channel Multi-Epi Super Junction MOSFETs

#### Features

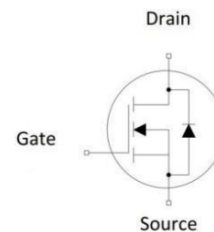
700V,7.0A  
 Very low FOM  $R_{DS(on)} \times Q_g$   
 100% UIS tested  
 RoHS compliant

#### Application

Power factor correction (PFC)  
 Switched mode power supplies (SMPS)  
 Uninterrupted power supply (UPS)



TO-252



Schematic Diagram

## Package Marking and Ordering Information

Device Marking	Device	OUTLINE	Device Package	TUBE (PCS)	Inner BOX (PCS)	Per Carton (PCS)
EC70R65E	EC70R65E	TAPING	TO-252	13inch	2500	25000

## Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Max.	Units
$V_{DSS}$	Drain-Source Voltage	700	V
$V_{GSS}$	Gate-Source Voltage	$\pm 30$	V
$I_D$	Continuous Drain Current	$T_c=25^\circ\text{C}$	7
		$T_c=100^\circ\text{C}$	4.4
$I_{DM}$	Pulsed Drain Current	21	A
$E_{AS}$	Single Pulsed Avalanche Energy	120	mJ
$P_D$	Power Dissipation	$T_c=25^\circ\text{C}$	63
$R_{\theta JC}$	Thermal Resistance, Junction to Case	2	$^\circ\text{C/W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to +150	$^\circ\text{C}$

## Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	700	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =700V, V <sub>GS</sub> =0V	-	-	1	μA
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>DS</sub> =0V, V <sub>GS</sub> =±30V	-	-	±100	nA
<b>On Characteristics</b>						
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2.5	-	4.0	V
R <sub>DS(on)</sub>	Static Drain-Source on-Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =3.5A	-	560	650	mΩ
<b>Dynamic Characteristics</b>						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V, f=1MHz	-	493	-	pF
C <sub>oss</sub>	Output Capacitance		-	32	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	1.6	-	pF
Q <sub>g</sub>	Total Gate Charge	V <sub>DD</sub> =560V, I <sub>D</sub> =3.5A, V <sub>GS</sub> =10V	-	13.3	-	nC
Q <sub>gs</sub>	Gate-Source Charge		-	2.8	-	nC
Q <sub>gd</sub>	Gate-Drain("Miller") Charge		-	4.7	-	nC
<b>Switching Characteristics</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =400V, I <sub>D</sub> =3.5A, R <sub>GEN</sub> =25Ω	-	11.6	-	ns
t <sub>r</sub>	Turn-on Rise Time		-	23	-	ns
t <sub>d(off)</sub>	Turn-off Delay Time		-	53	-	ns
t <sub>f</sub>	Turn-off Fall Time		-	35.8	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
V <sub>SD</sub>	Drain to Source Diode Forward Voltage	V <sub>GS</sub> =0V, I <sub>F</sub> =3.5A	-	0.85	-	V
t <sub>rr</sub>	Body Diode Reverse Recovery Time	V <sub>R</sub> =50V I <sub>F</sub> =3.5A, di/dt=100A/μs	-	201.4	-	ns
Q <sub>rr</sub>	Body Diode Reverse Recovery Charge		-	1.3	-	μC

Typical Performance Characteristics

Figure 1. Output Characteristics

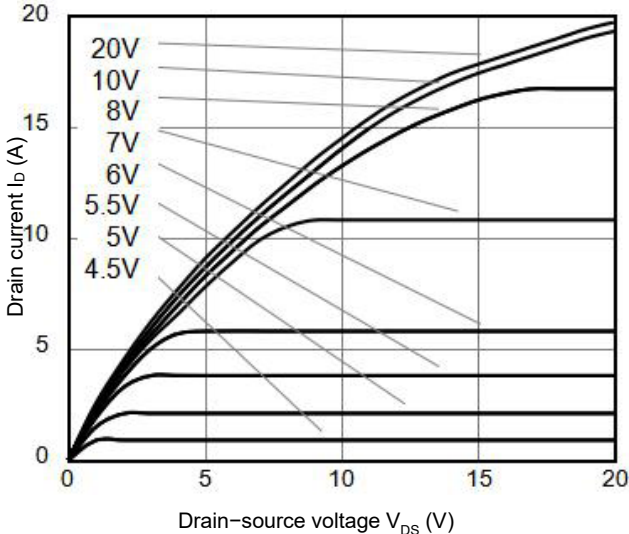


Figure 2. Transfer Characteristics

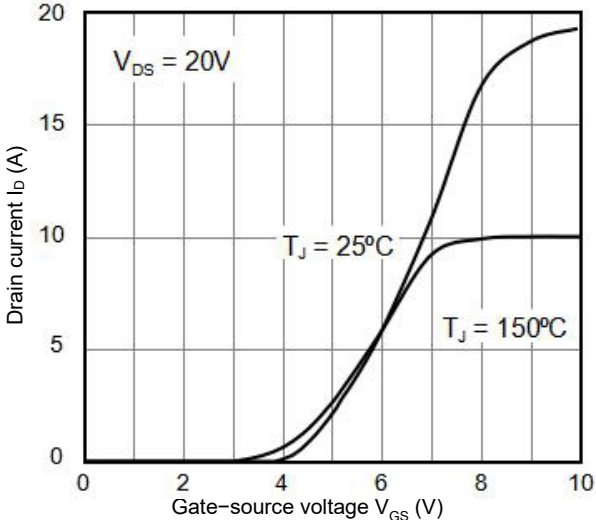


Figure 3. On-Resistance vs. Drain Current

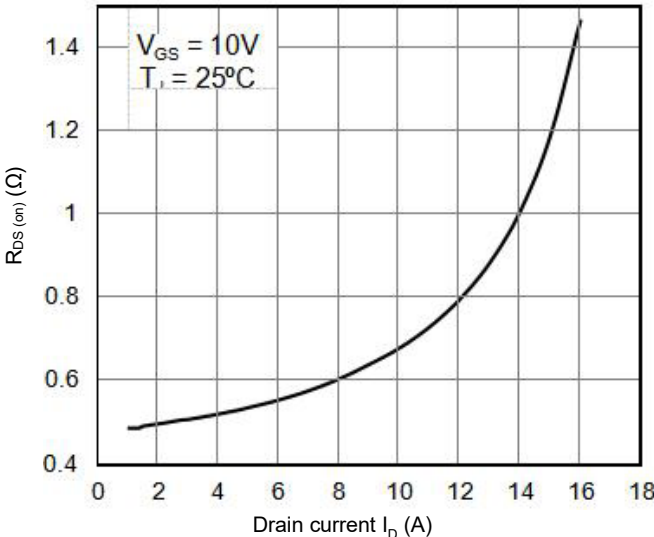


Figure 4. Capacitance Characteristics

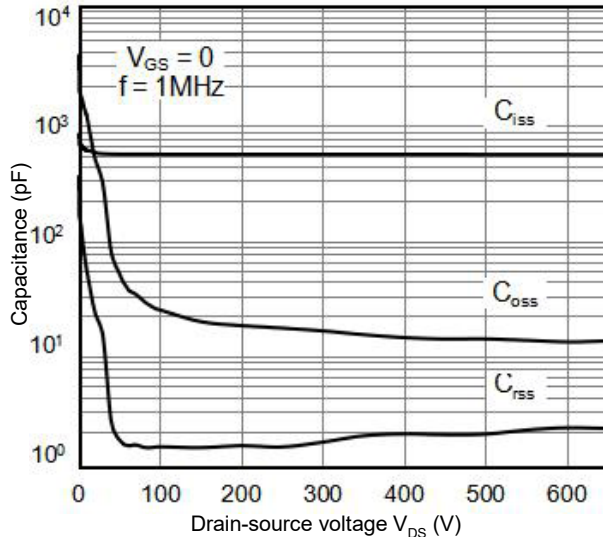


Figure 5. Gate Charge Characteristics

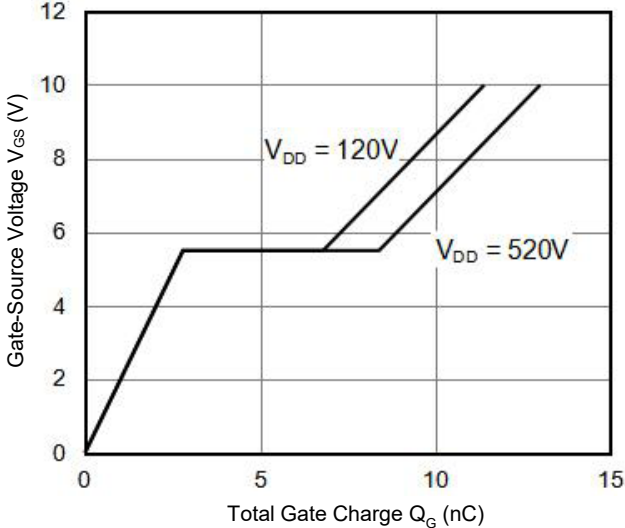


Figure 6. Body Diode Forward Voltage

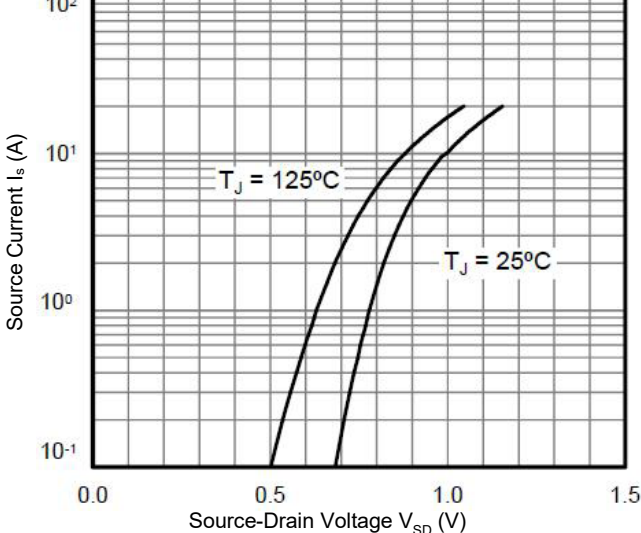


Figure 7. Breakdown Voltage vs. Temperature

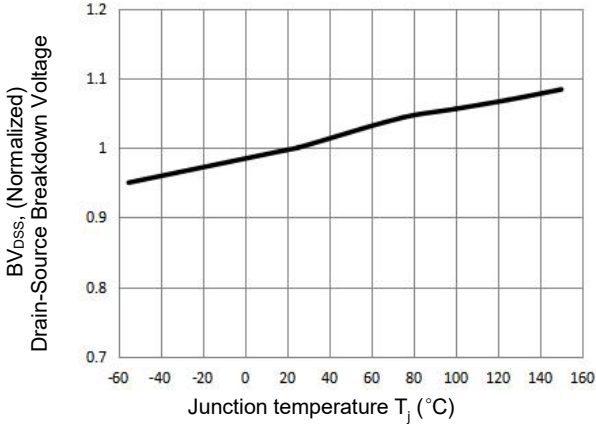


Figure 9. Maximum Safe Operating Area TO-252/TO-251

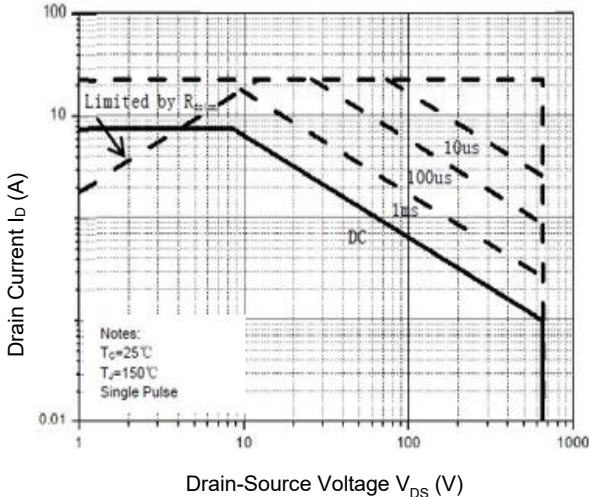


Figure 8. On-Resistance vs. Temperature

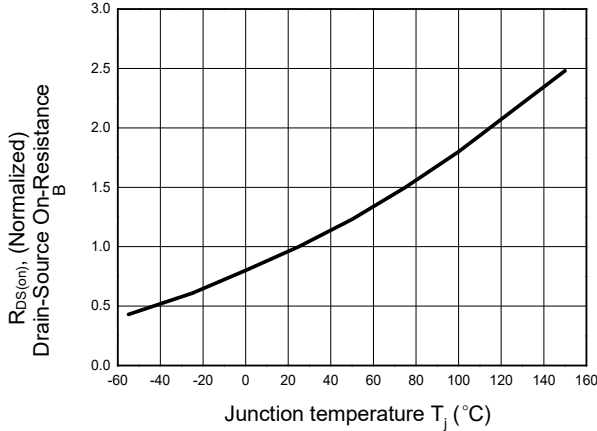
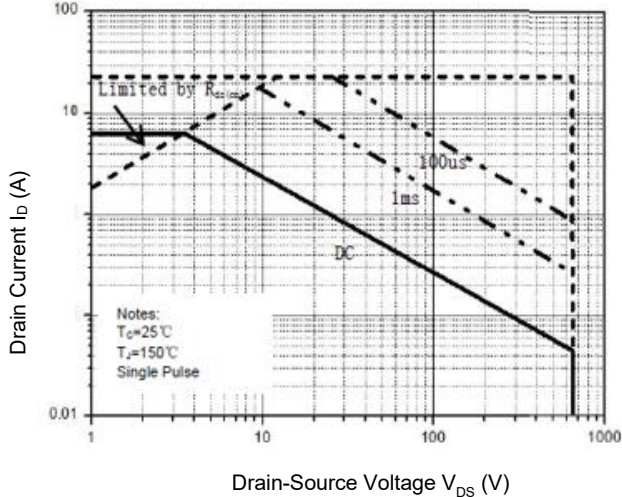
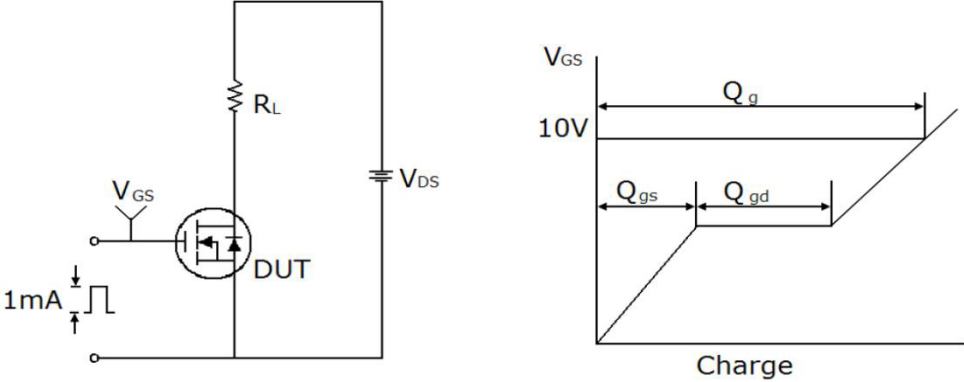


Figure 10. Maximum Safe Operating Area TO-220F

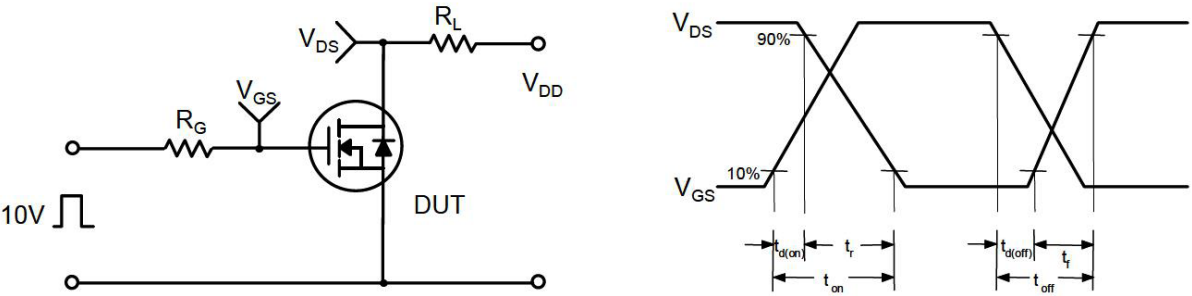


Test Circuit

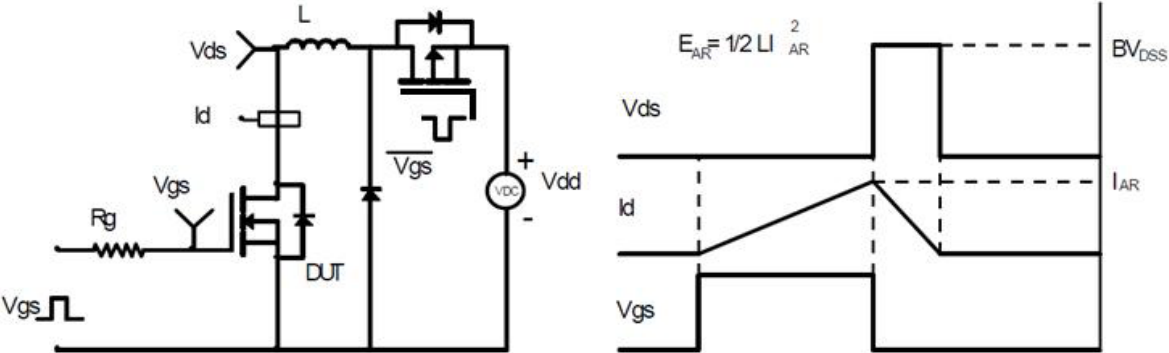
Gate Charge Test Circuit & Waveform



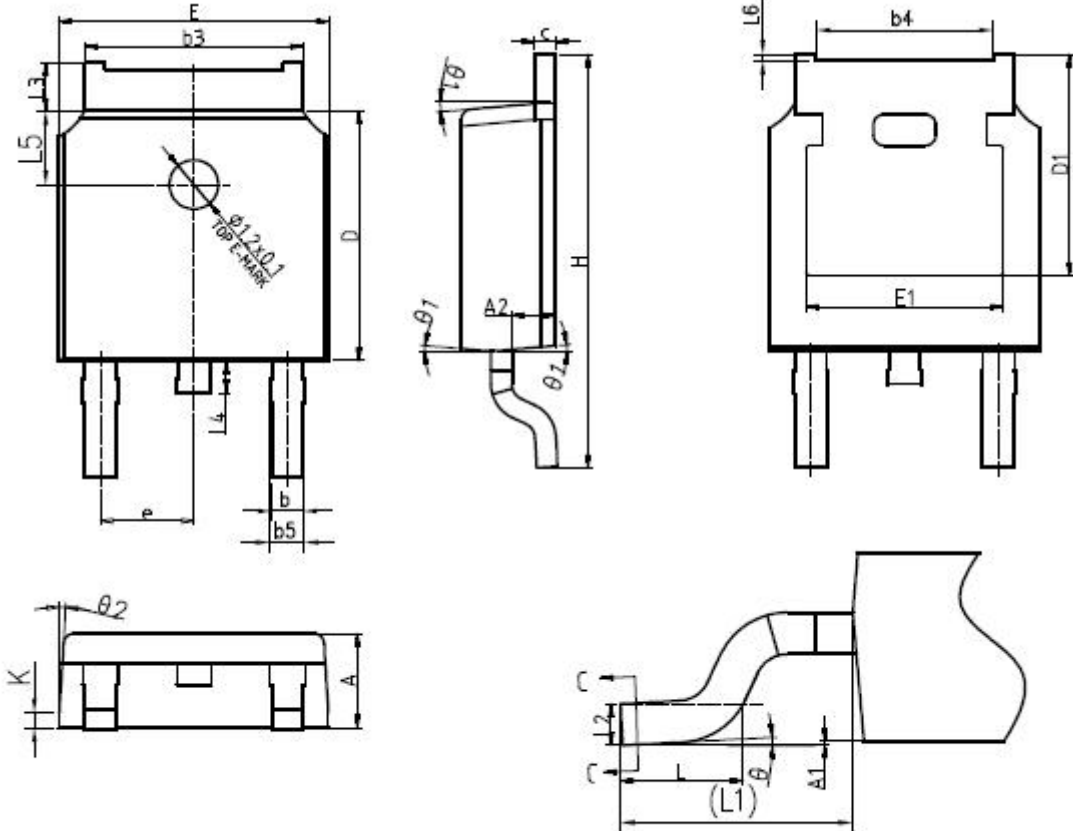
Switching Test Circuit & Waveform



Unclamped Inductive Switching Test Circuit & Waveform



Package Mechanical Data-TO-252



单位: mm

SYMBOL	mm		
	MIN	NOM	MAX
*A	2.20	2.30	2.38
*A1	0.00	-	0.10
A2	0.97	1.07	1.17
*b	0.72	0.78	0.85
b1	0.71	0.76	0.81
*b3	5.23	5.33	5.46
b4	4.27	4.32	4.37
b5	0.72	0.88	0.93
*c	0.47	0.53	0.58
c1	0.46	0.51	0.56
*D	6.00	6.10	6.20
D1	5.30REF		

*E	6.50	6.60	6.70
E1	4.70	4.83	4.92
*e	2.286BSC		
L	1.40	1.50	1.70
L1	2.90REF		
L2	0.51BSC		
*L3	0.90	-	1.25
*L4	0.60	0.80	1.00
L5	1.70	1.80	1.90
L6	0	0.047	0.123
$\theta$	0°	-	8°
* $\theta 1$	5°	7°	9°
$\theta 2$	5°	7°	9°
K	0.40REF		

Product Naming Rules

